

Progress in the CMOS Pixel TPC concept

Jan Timmermans - NIKHEF

- Micro Pattern Gas Detector: pixelised anode + Micromegas or GEM
- Integration of grid and readout: InGrid
- 3D readout: TimePix
- Discharge protection
- Future developments

Groups involved: Bonn, CEA Saclay, CERN, Freiburg, NIKHEF

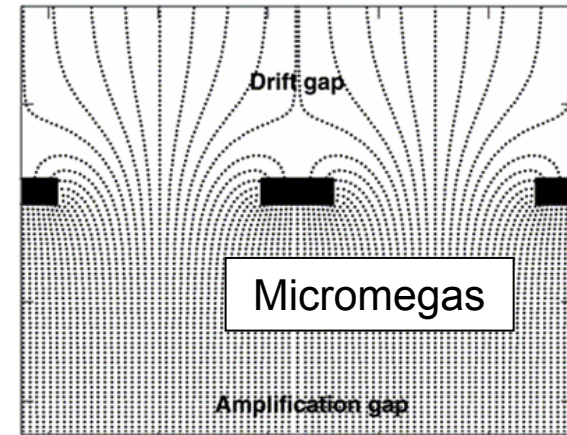
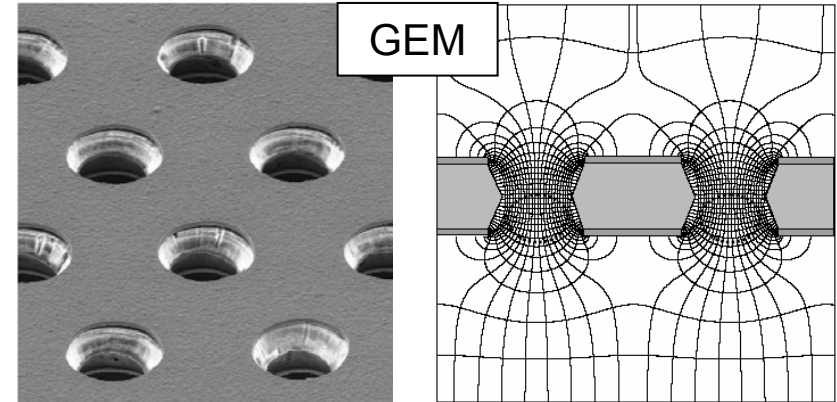
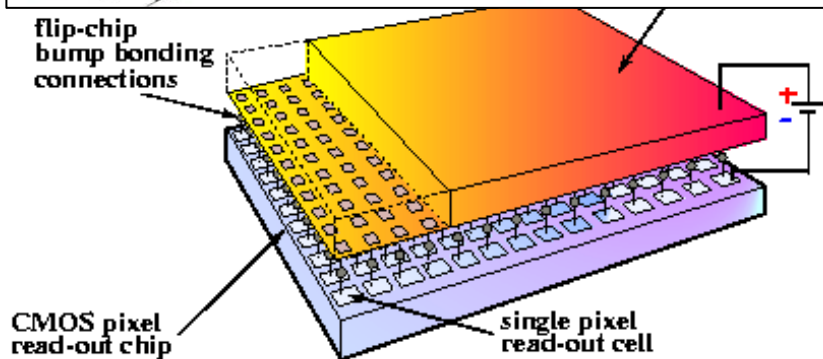
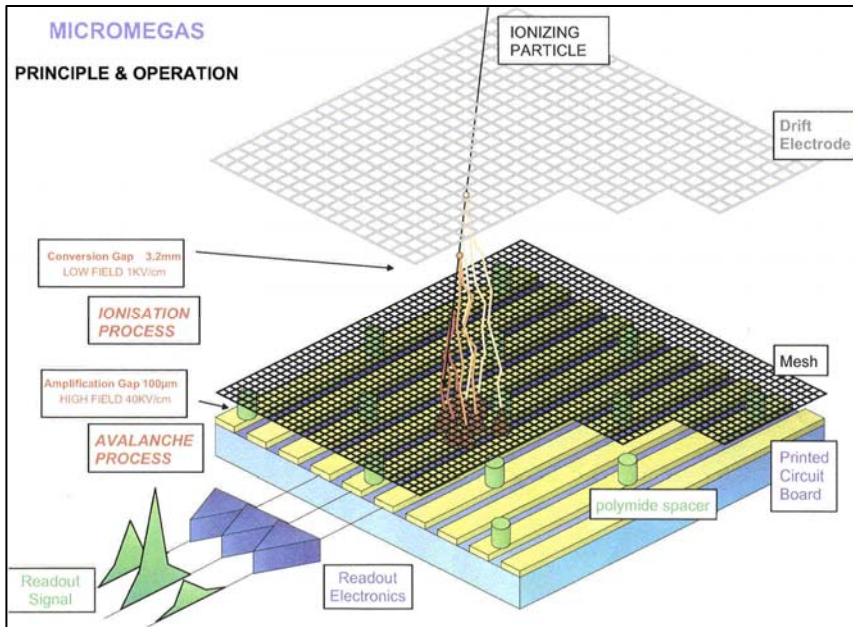
Goals

- **Gas multiplication** GEM or Micromegas foil(s)
- Charge collection with **granularity matching primary ionisation cluster spread**
(this needs **sufficiently low diffusion gas**)
- Investigate measurement dE/dx using **cluster counting**

- 2D “proof of principle” based on existing **Medipix2** readout chip: **achieved**
- Add 3rd coordinate: **Medipix2** → **TimePix: available; first results**
- Integrate grid with pixel chip: **InGrid: some results**

Micro Patterned Gaseous Detectors

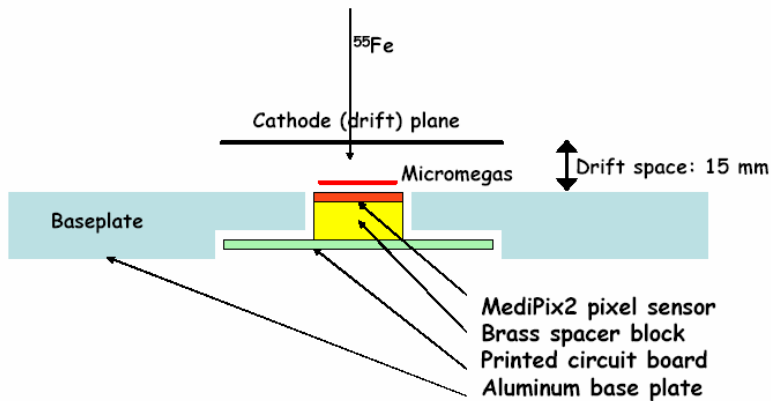
- High field created by Gas Gain Grids
- Most popular: GEM & Micromegas



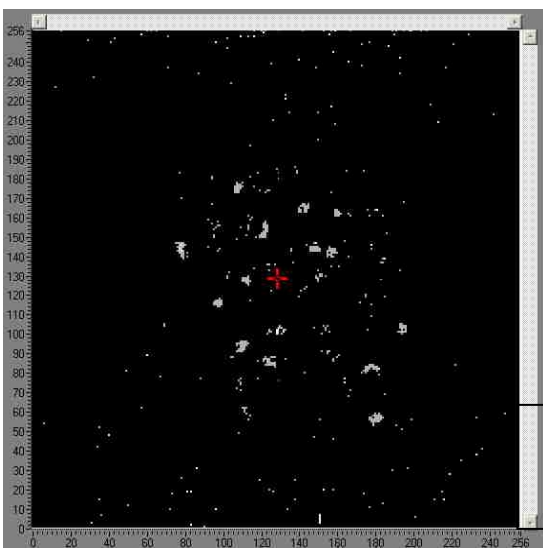
Use 'naked' CMOS pixel readout chip as anode

Results pixel readout gas detectors

NIKHEF-Saclay-CERN-Twente



Very strong E-field above (CMOS) MediPix!



Ar/isobutane
95/5

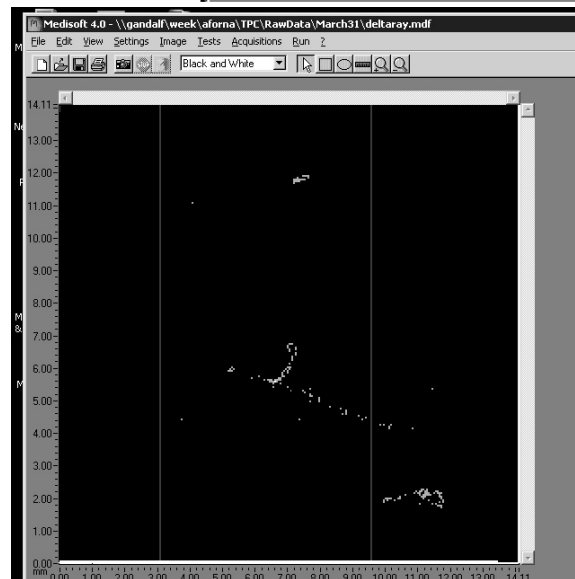
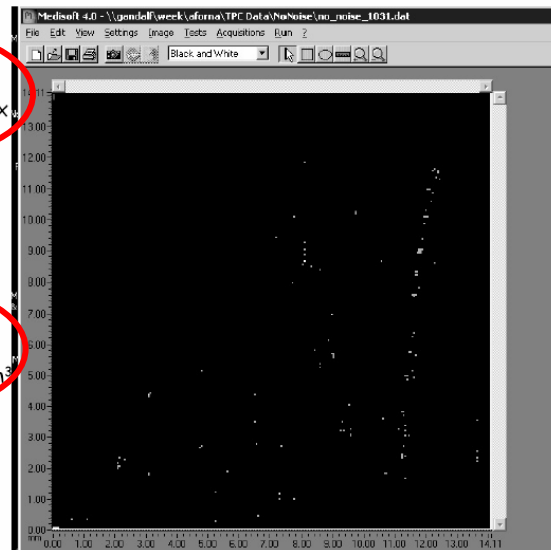
55x55 μm^2
pixels

He/Isobutane
80/20
Modified MediPix

31 March 2004

Sensitive area:
14 x 14 x 15 mm³

Drift direction:
Vertical
max = 15 mm



δ ray

Observation of min. ionising cosmic muons: high spatial resolution + individual cluster counting !

February 5, 2007

Tracking Review Beijing

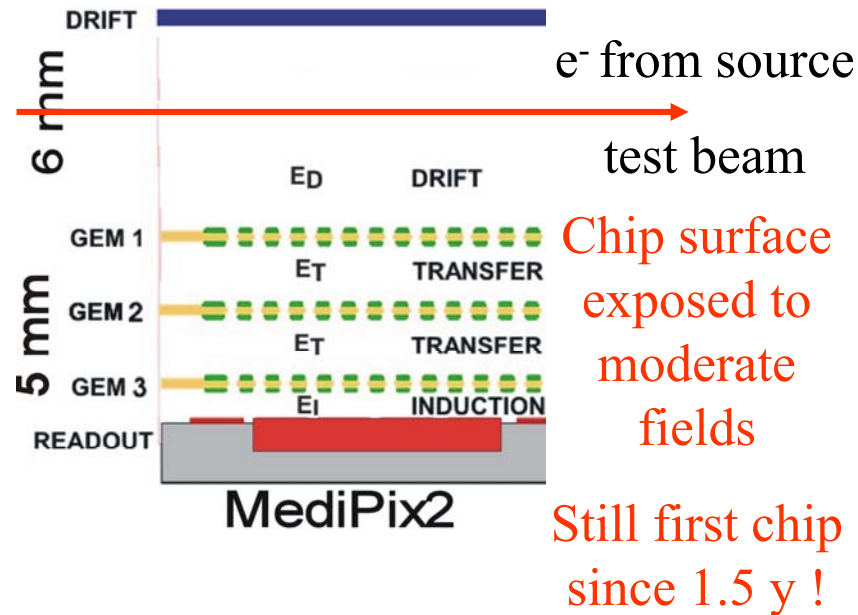
4

NIM A540 (2005) 295 (physics/0409048)

GEM-TimePix Project

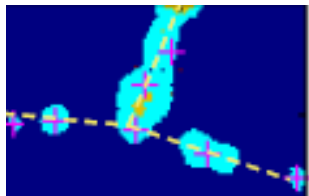
Institute of Physics, Albert-Ludwigs-Universität Freiburg

- Micro Pattern Gas Detectors (MPGD): high resolution readout and high rates
- pixelated readout offers high resolution
Digital Bubble Chamber
- a **TPC** at the **ILC** needs excellent momentum resolution =>GEM-TimePix for end plate readout
 - Cluster counting as a goal

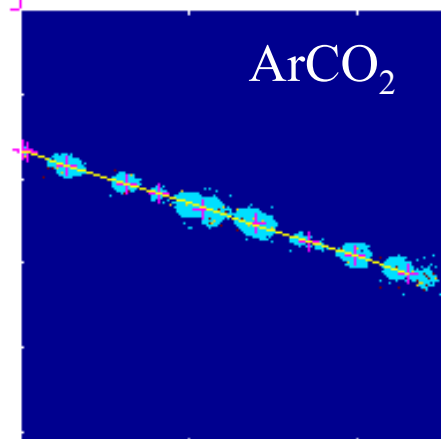


Results from MediPix Prototype setup:

For ArCO₂ and HeCO₂: point/cluster resolution determined with different algorithms between 50 - 60 μ m



δ -electron in HeCO₂



Charge deposition on the MediPix Chip electron track from ¹⁰⁶Ru source and straight line fit

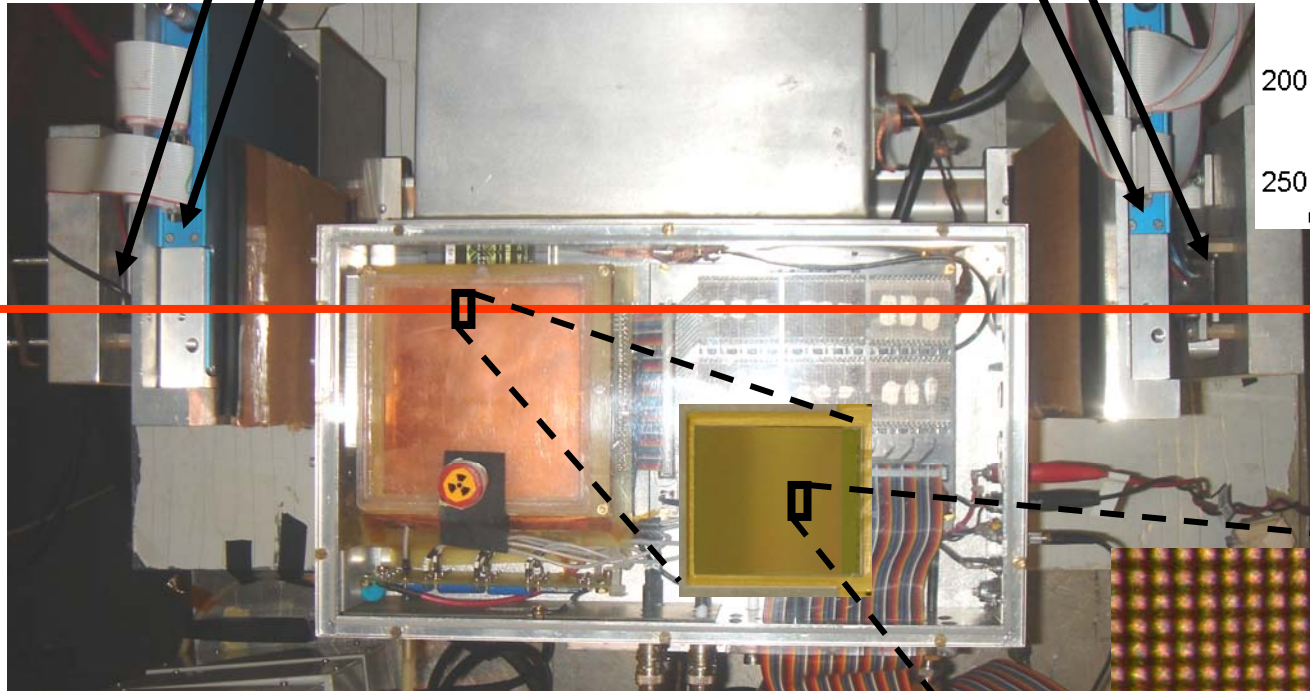
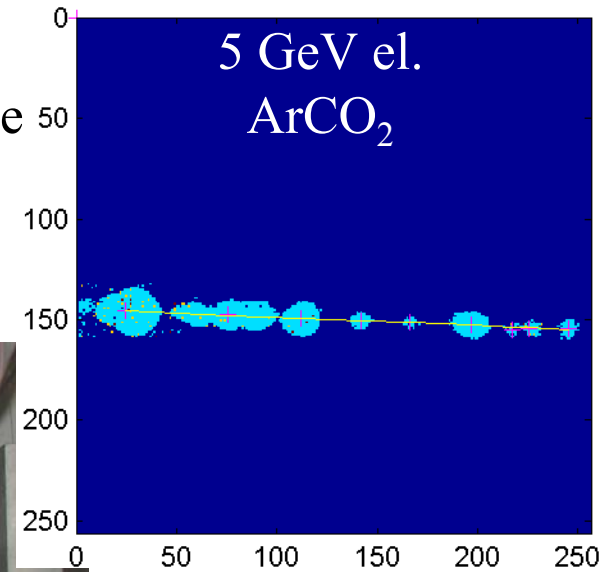
Test beam event

diff(1)=36.6 μm

multiple scattering negligible on MediPix/TimePix scale

trigger counters ~ 8 mm wide

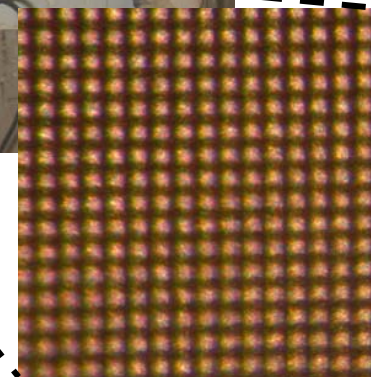
Si telescope (~ 20 μm precision)



e^- from DESY II

GEM stack of
 10×10 cm²

MediPix2/TimePix
chip 14×14 mm²

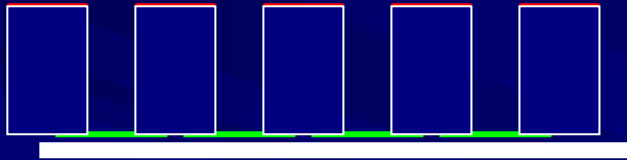


pitch of
pixels
 55 μm

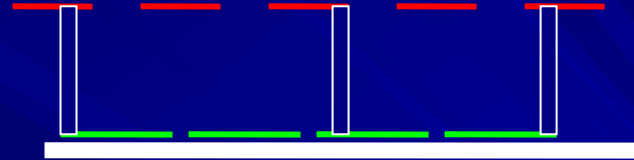
InGrid

Integrate GEM/Micromegas and pixel sensor

‘GEM’

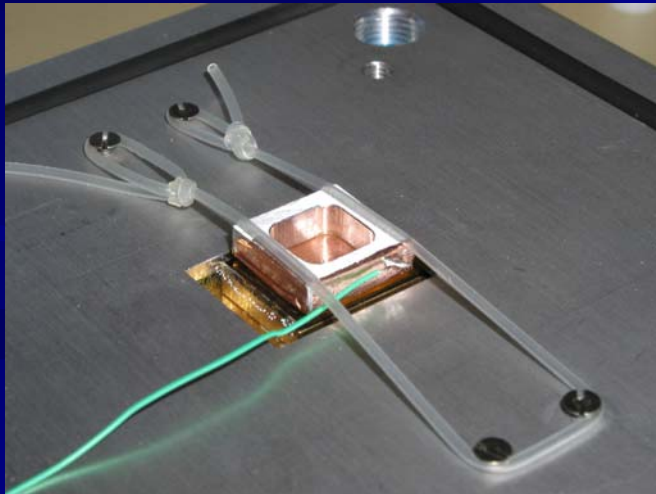


‘Micromegas’



By ‘wafer post processing’

4" wafer

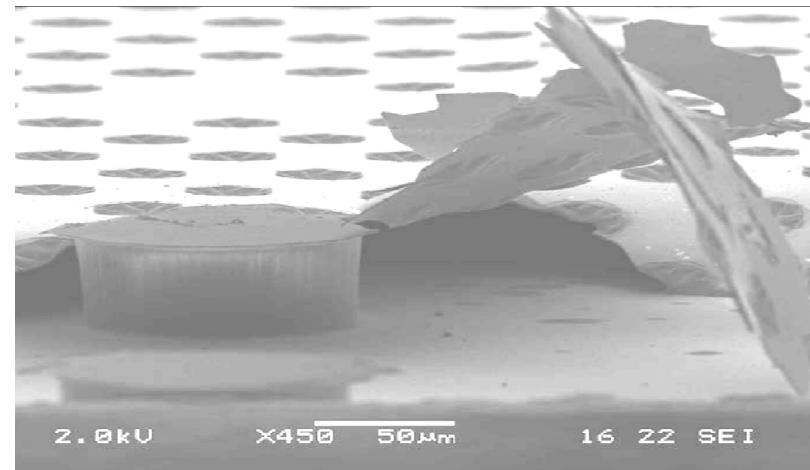
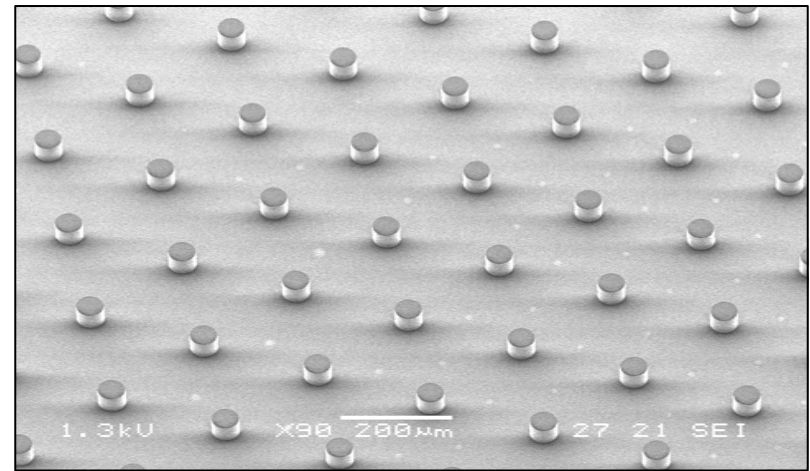
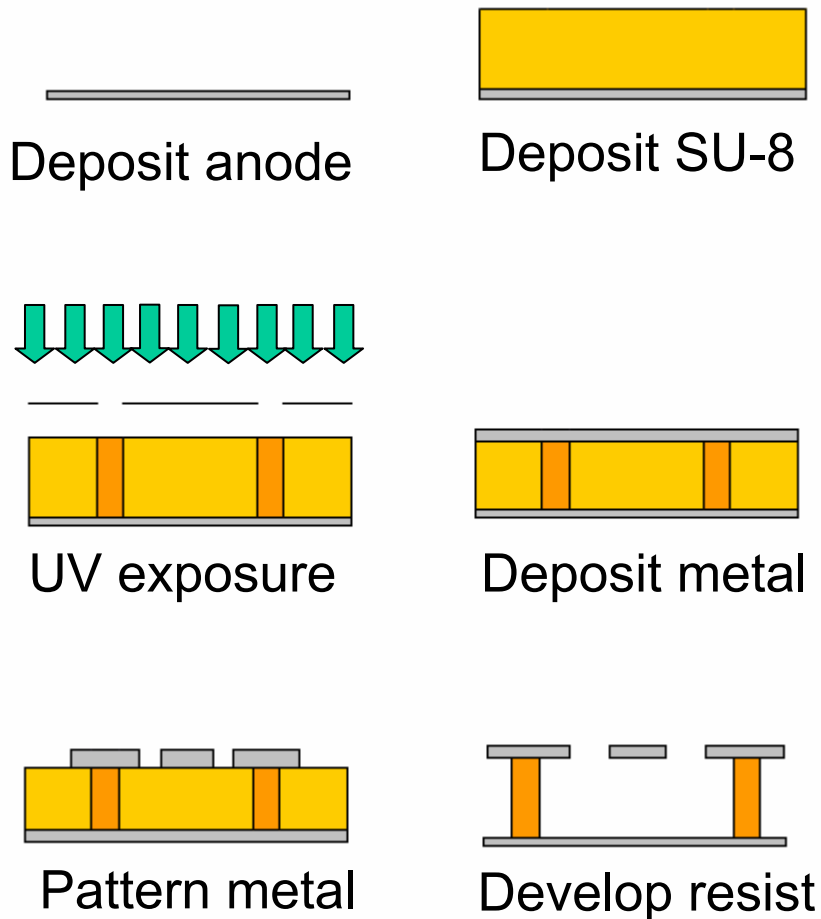


February 5, 2007

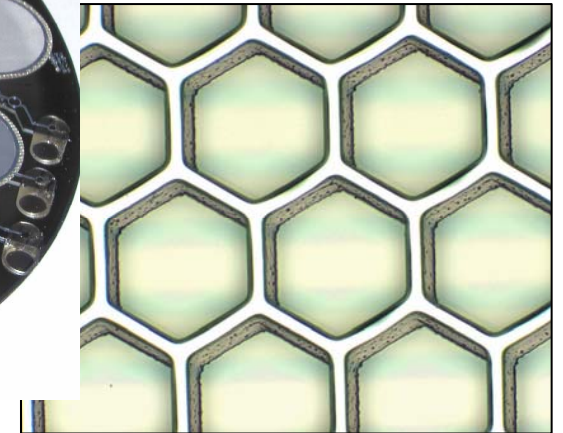
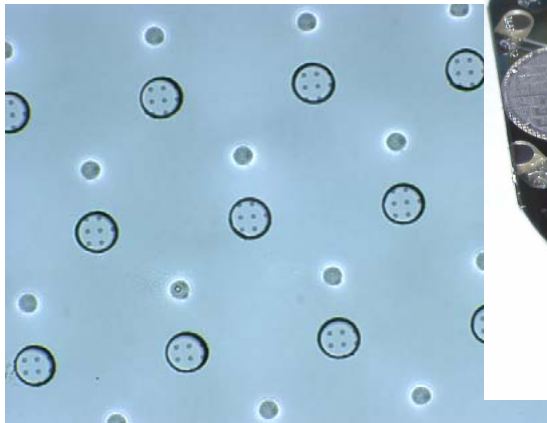
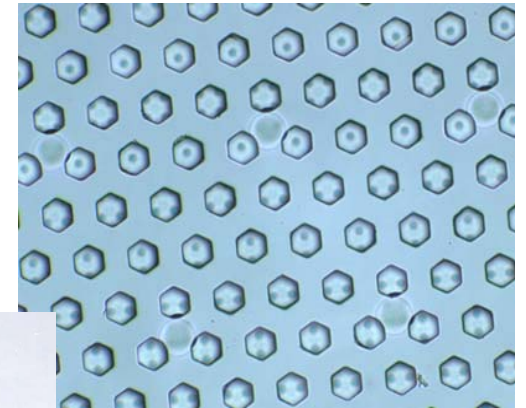
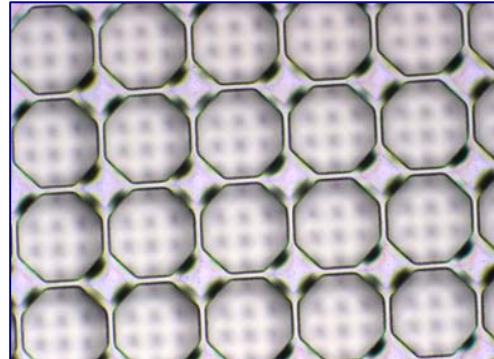
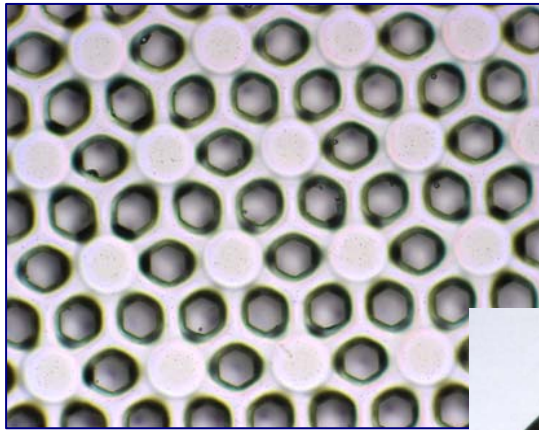
Tracking Re

19 different fields of 15 mm \varnothing
2 bonding pads / fields

NIKHEF/Twente: InGrid (Integrated Grid)

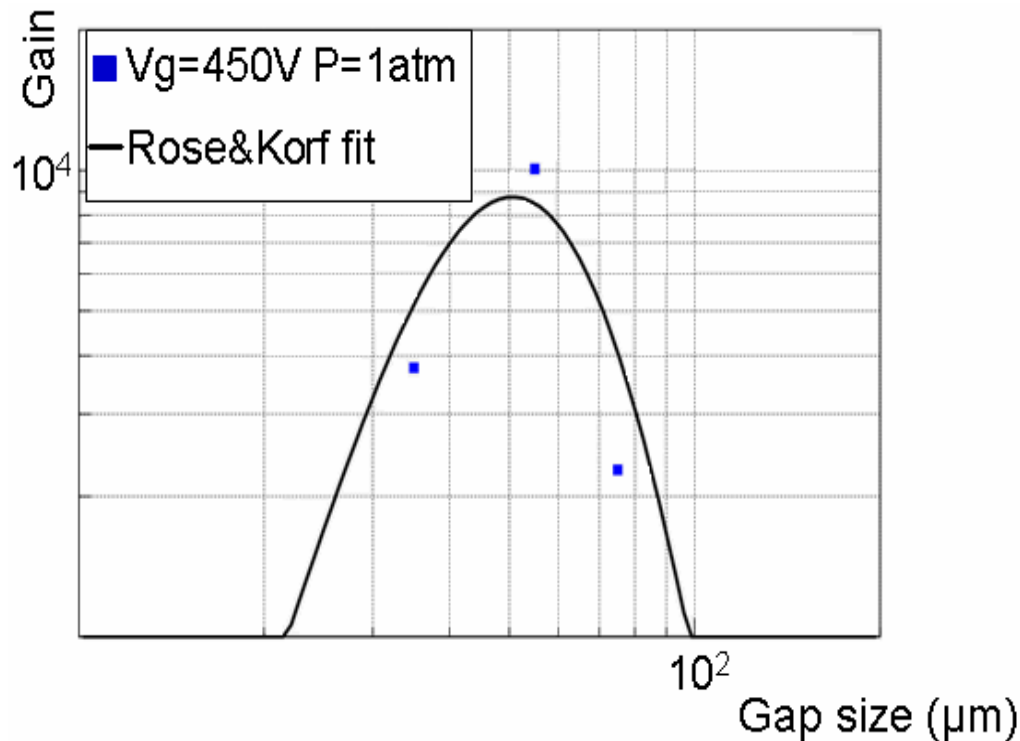


Any field structure feasible



Gain for different gap sizes (many other measurements in backup slides)

Maximum predicted in gain vs gap curve



$$M = e^{\alpha d}$$

d gap thickness

$$\alpha = pAe^{-Bp/E}$$

Rose & Korff

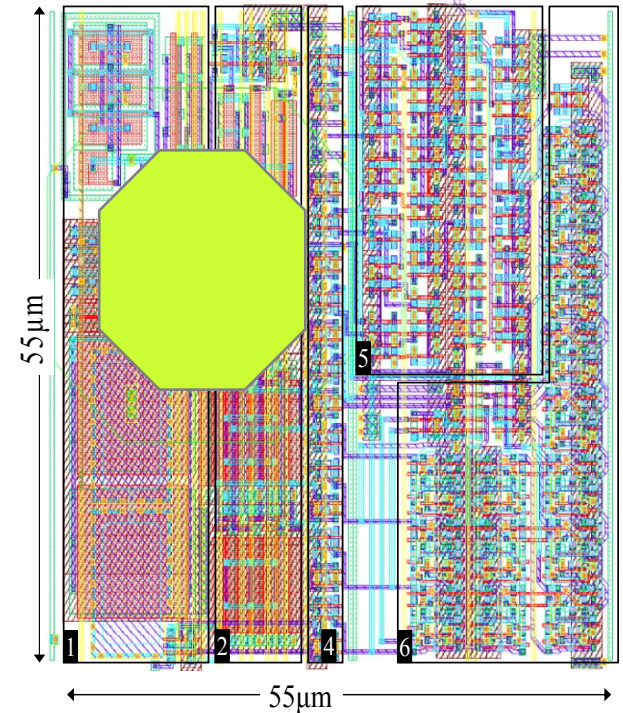
p pressure

A, B depend on gasmixture

TimePix (EUDET: Bonn, Freiburg, Saclay, CERN, NIKHEF)



- Distribute clock to full 256x256 pixel matrix (50-100-160MHz)
 - Enable counting by first hit after 'shutter' opens, until 'shutter' closes (common stop); also time-over-threshold possible
 - Dynamic range $2^{14} \times 10 \text{ ns} = 160 \mu\text{s}$
 - (for the time being) no zero-suppress to remain fully compatible with Medipix2
 - Shaping time $\sim 200 \text{ ns}$
 - Keep same chip-size, pixel-size, readout protocol
 - 1st full reticle submit done July 2006;
- IT WORKS! Now doing tests in gas detectors.**



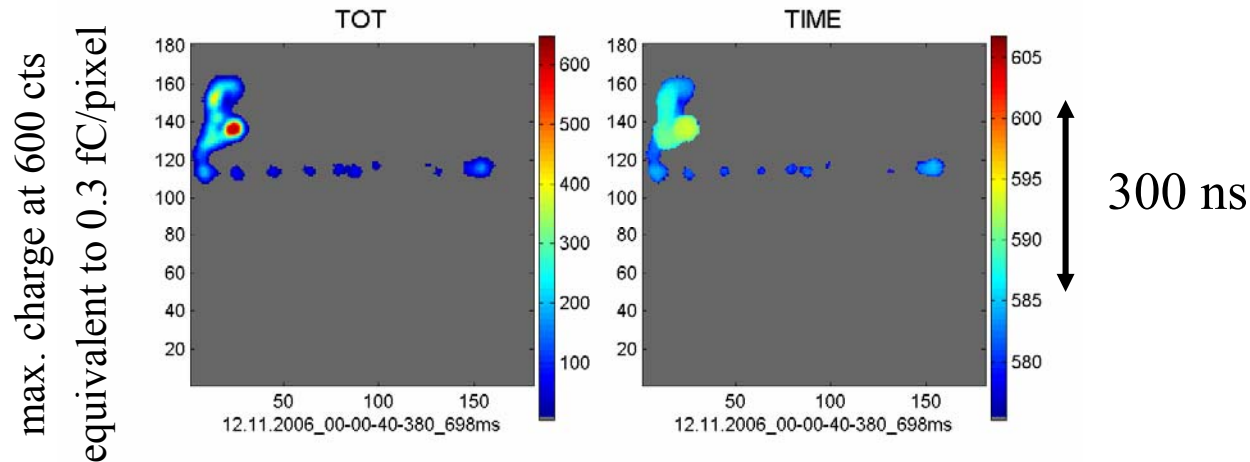
TimePix Test Beam Results (TimePix + GEM setup)

- Point resolution from a straight line fit averaged over all drift volume of 6mm: $39.3 \pm 1.3 \mu\text{m}$ for Ar/CO₂
- Resolution near the first GEM (selected by Si-telescope and using the parametrisation of $\sigma_{mean}^2 = \sigma_0^2 + \frac{D_t^2 \cdot y}{n_{cl}^{el}}$)
 - $25.0 \pm 2 \mu\text{m}$ for Ar/CO₂
 - $30.0 \pm 2 \mu\text{m}$ for HeCO₂

Events taken with the mixed mode

- Gas mixture HeCO₂
- delta-electrons, example of a ~6 keV:

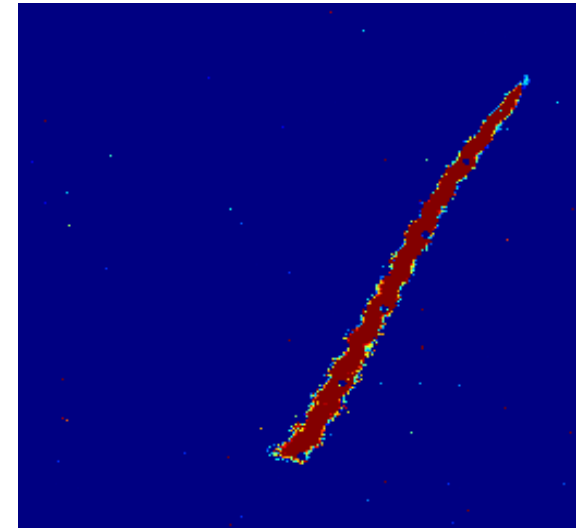
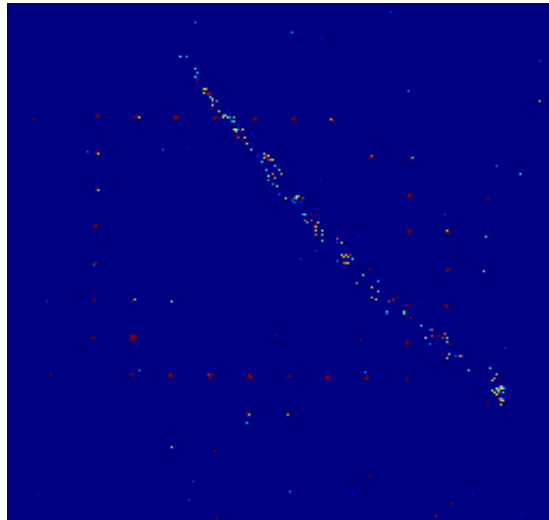
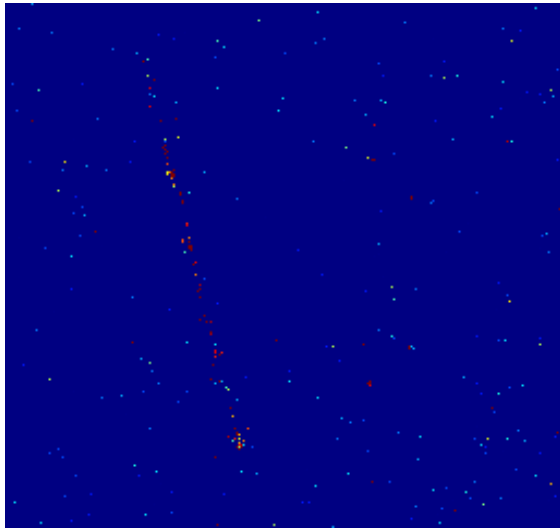
left side TOT (charge), left side: Time of arrival



First tracks with TimePix+Micromegas: cosmics + α particle

$V_{\text{grid}} = -400$ V; gain ~ 6000

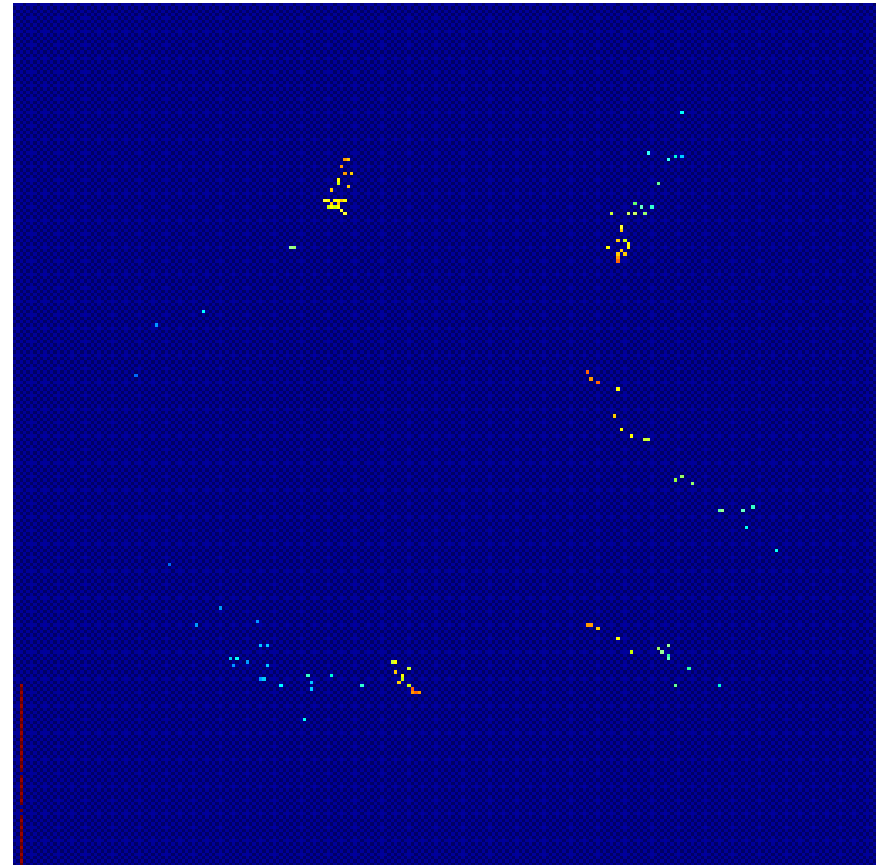
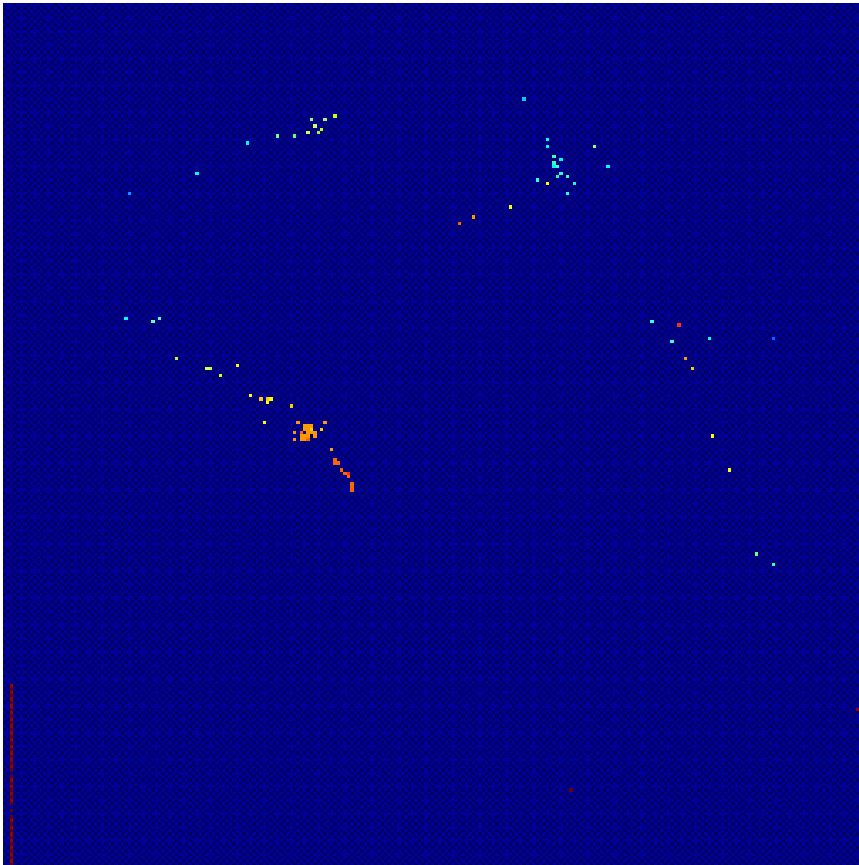
He/Isobutane 80/20



Acquisition ('shutter') time ~ 1 sec

And triggered cosmics (sum of several triggers)

Shutter time = 15 μ s

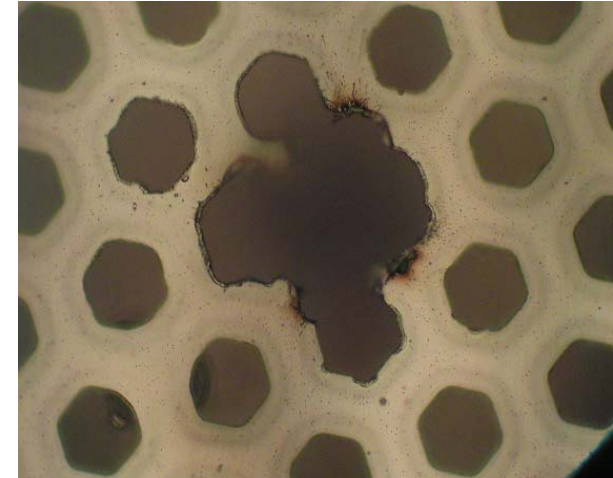
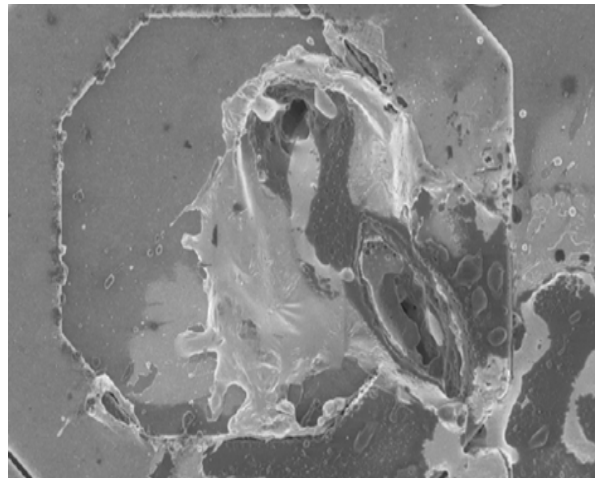
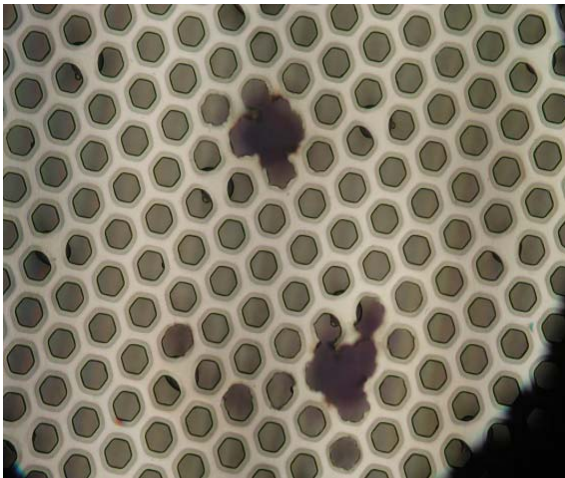


TimePix chip stayed alive for 40 days with He/isobutane

And 'died' after 1.5 day with Ar/isobutane 80/20

Sparking

- Chip faces 80kV/cm with no protection (unlike the GEM setup; 1.5 yr using same chip)
- Degradation of the field, or total destruction of grid but also CMOS chip

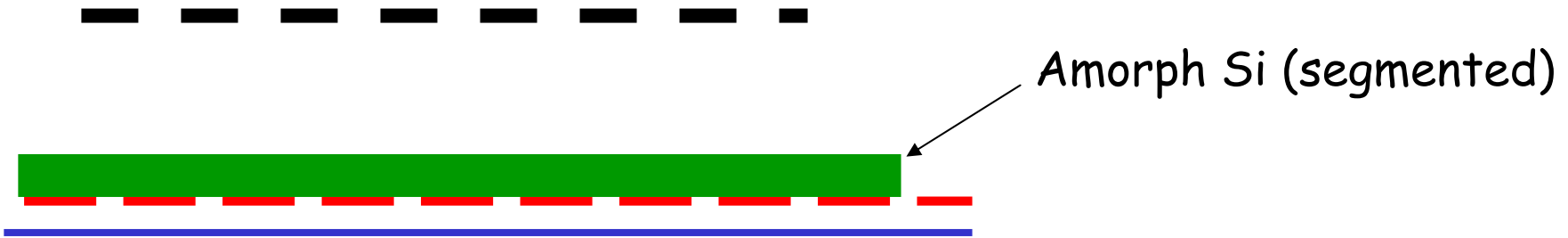


10 μ m

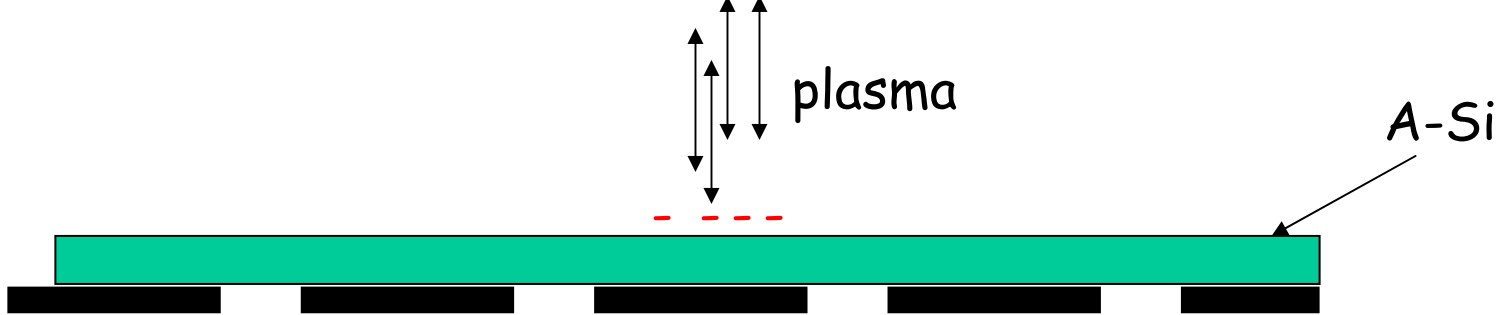
CMOS Chip protection against

- discharges
- sparks
- HV breakdowns
- too large signals

Silicon Protection: SiProt



Empirical method:
Try RPC technology



- RPC principle: reduction of local E-field
- Avalanche charge: electrostatic induction towards input pad
- Specific resistance:
 - high enough to 'block' avalanche charge
 - low enough to flow signal current
 - layer thickness $4 \mu\text{m}$, $R_{\text{vol}} = 0.2 \text{ G}\Omega/\text{cm}$

Technology

A-Si deposit possible in general; avoid wafers get too hot



Univ. of Neuchatel/IMT/P. Jarron (CERN) uses this for integrated X-ray sensor/convertor on MediPix 2

Test: put Thorium in gas: Radon α -decays:

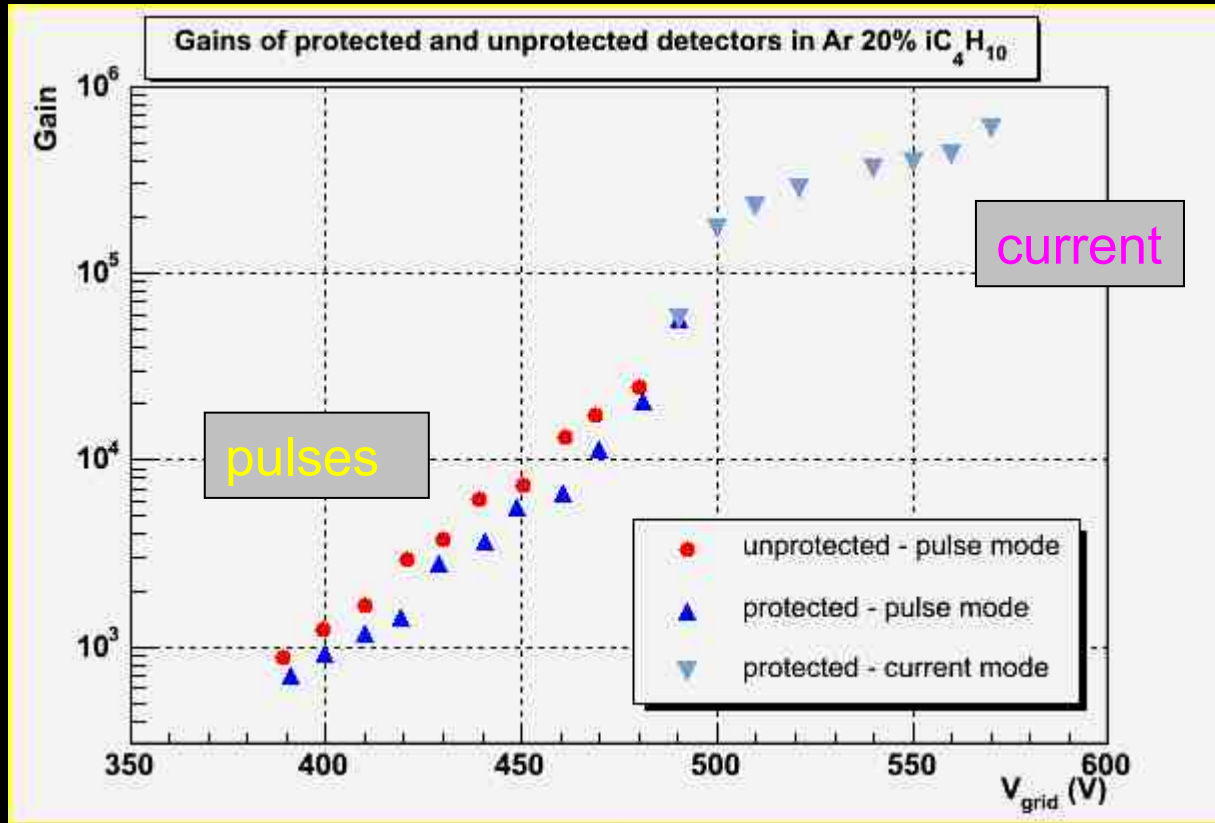
- large (proportional) signals
- Discharges: like short circuits

Iron 55 source

Gain

Look at the pulses from a pre amplifier (low grid voltage)

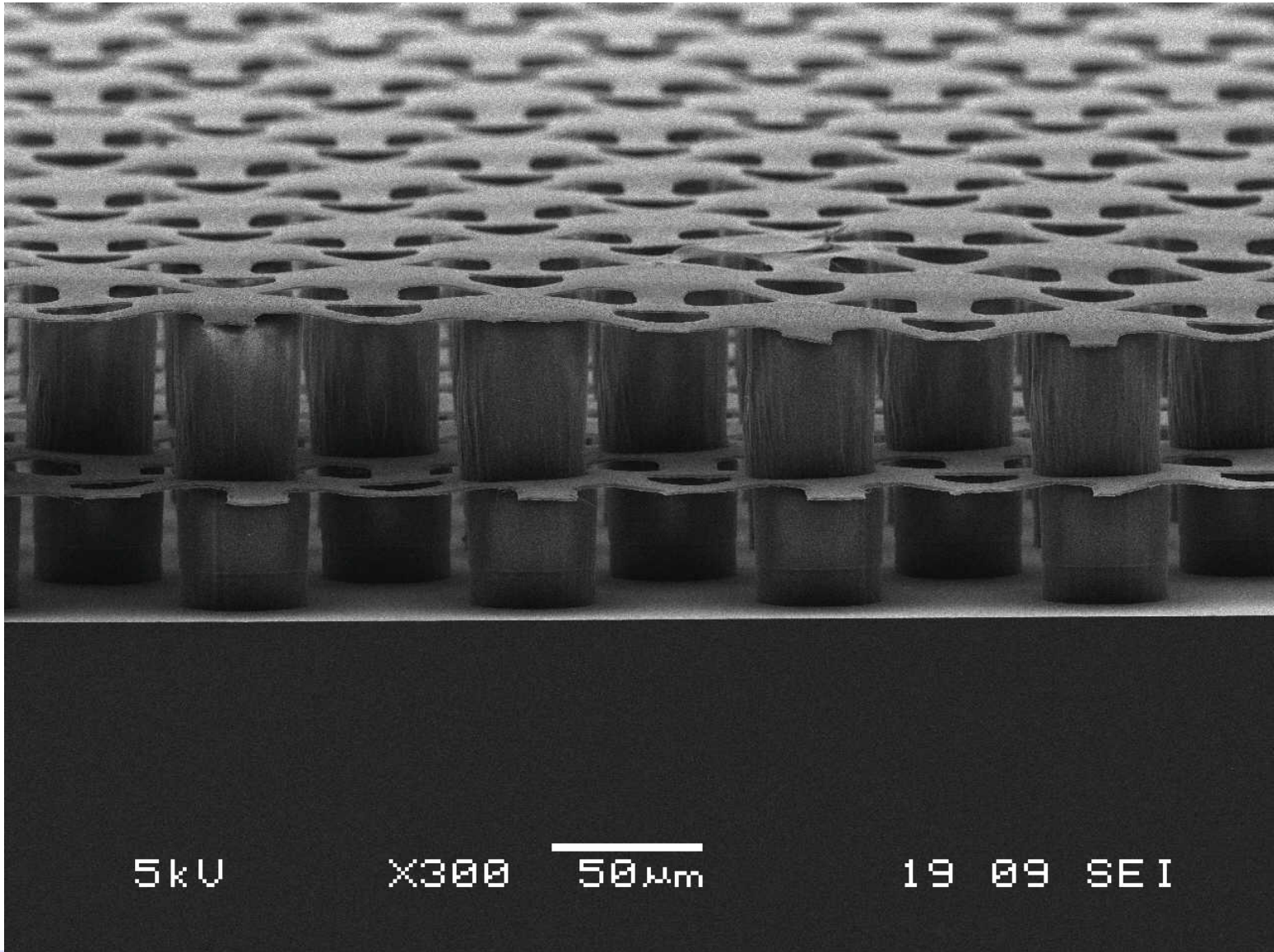
Look at the current flowing through the power supply (high grid voltage)



No sparks up to 570 V on the grid !

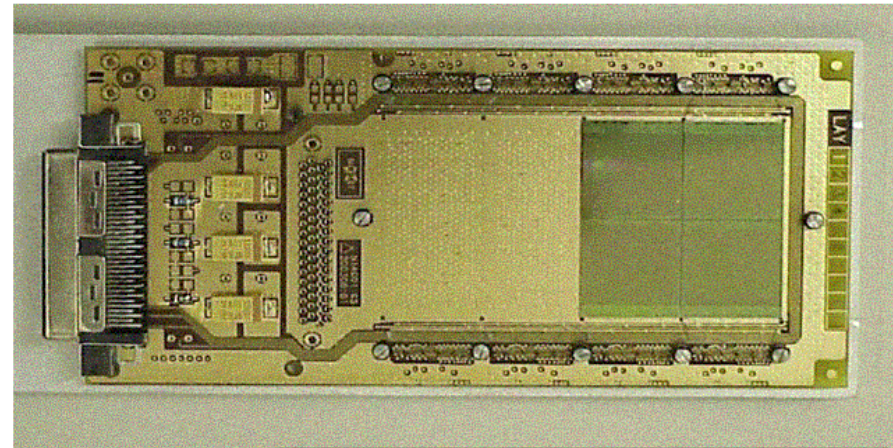
Alternative:

TwinGrid



Further Developments

- **Chip tiling:** large(r) detector surfaces
(2x2, 2x4 chips)
- **Through Si connectivity:** avoiding bonding wires
- **Fast readout technology**
(~5 Gb/s)
- **Intermediate size TPC**
- **Endplate module for LP**



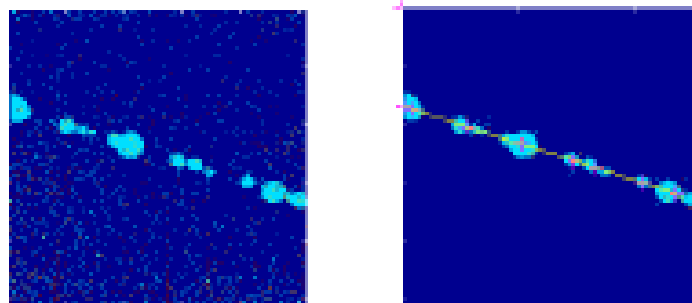
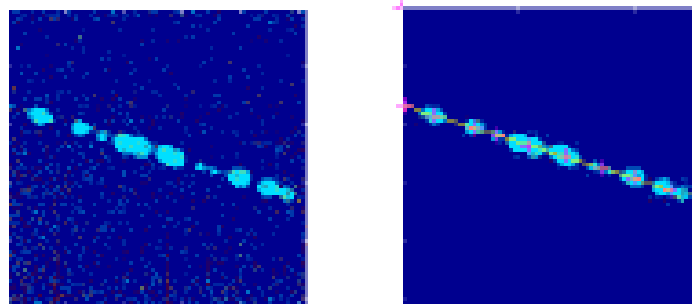
- Octal chip board:
56 mm x 110 mm
12-layer pcb

Backup slides



Some events with fits (β source)

(from Freiburg GEM+Medipix setup - Andreas Bamberger)



Triple GEM

Total gain $\sim 60k$

$\sim 50 \mu m$ resolution

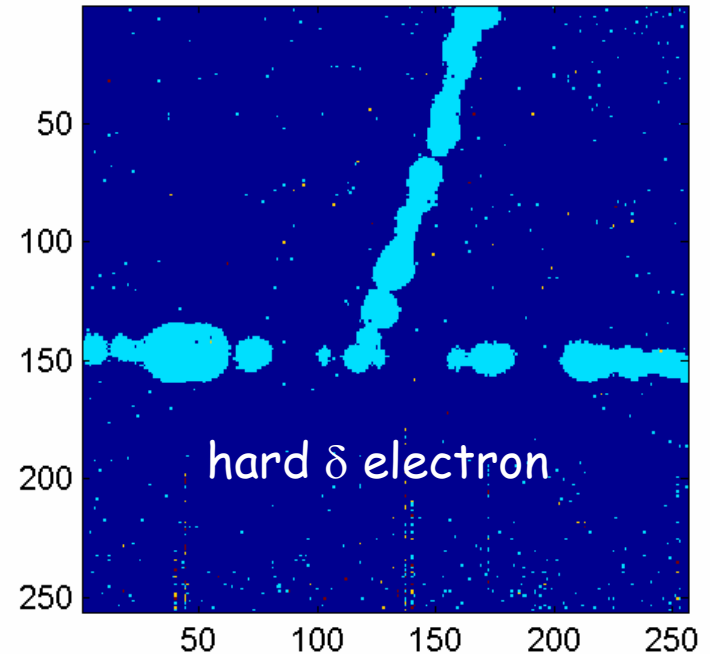
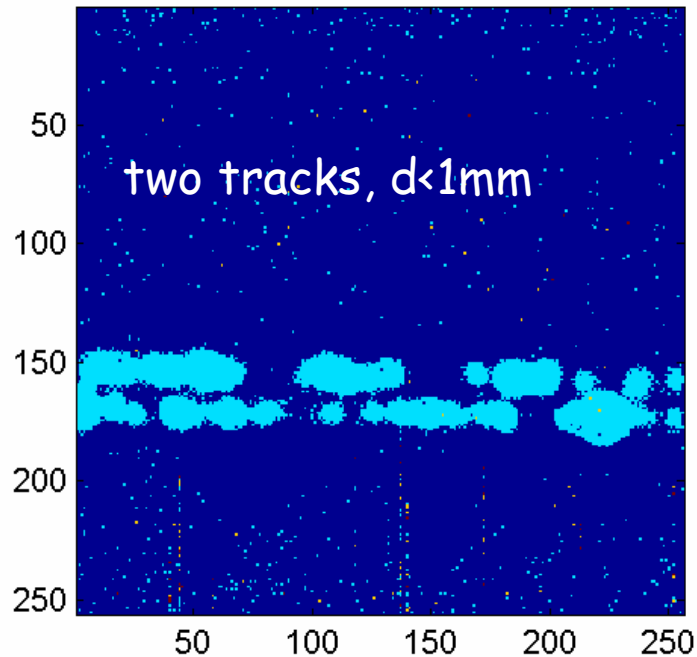
Difference between Micromegas and GEM setup understood (simulation Michael Hauschild/CERN)

4. Testbeam at DESY: 3- GEM+Medipix

Freiburg
Bonn

A28.09.2006_16-07-17-156_648ms.dat

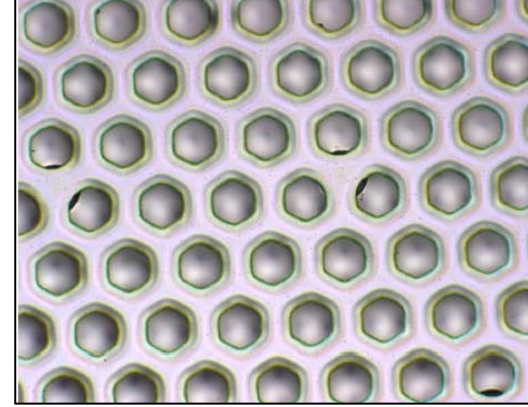
B03.10.2006_13-20-01-796_348ms.dat



Lots of data to be analyzed
Still the same Medipix chip as 1.5 years ago
Prepare for Testbeam with Timepix in same setup a.s.a.p.

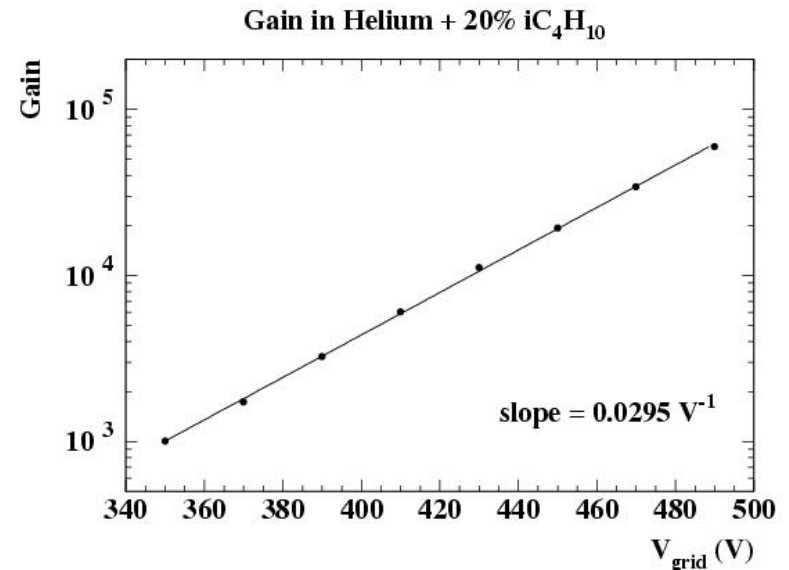
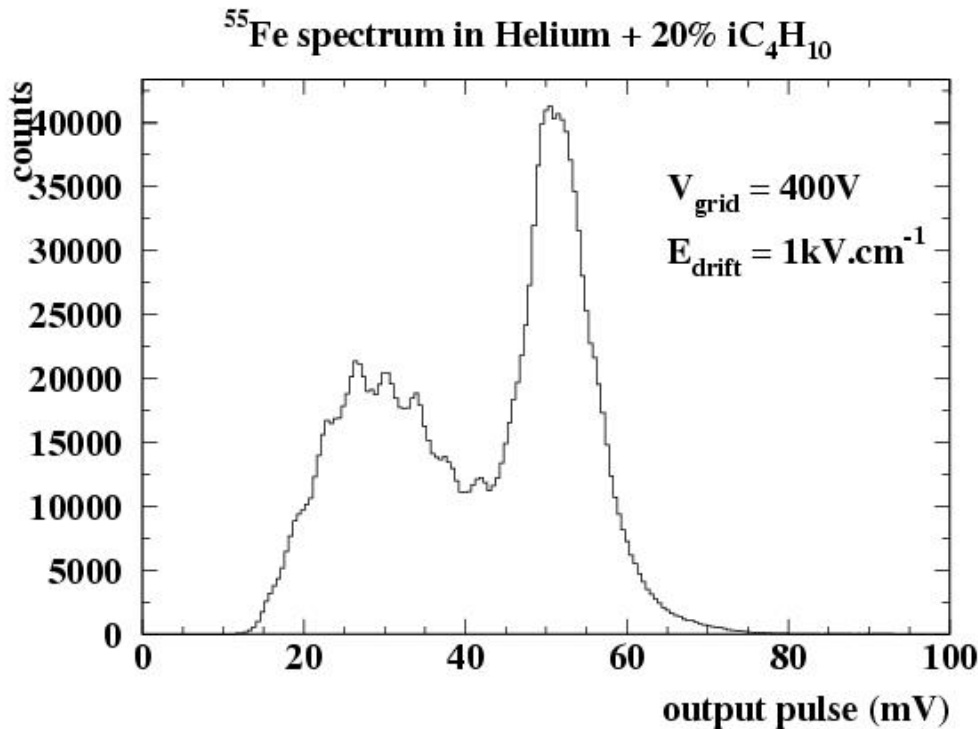
Measuring the InGrid signals

(NIM A556 (2006) 490)



(After 9 months of process tuning and unsuccessful trials)

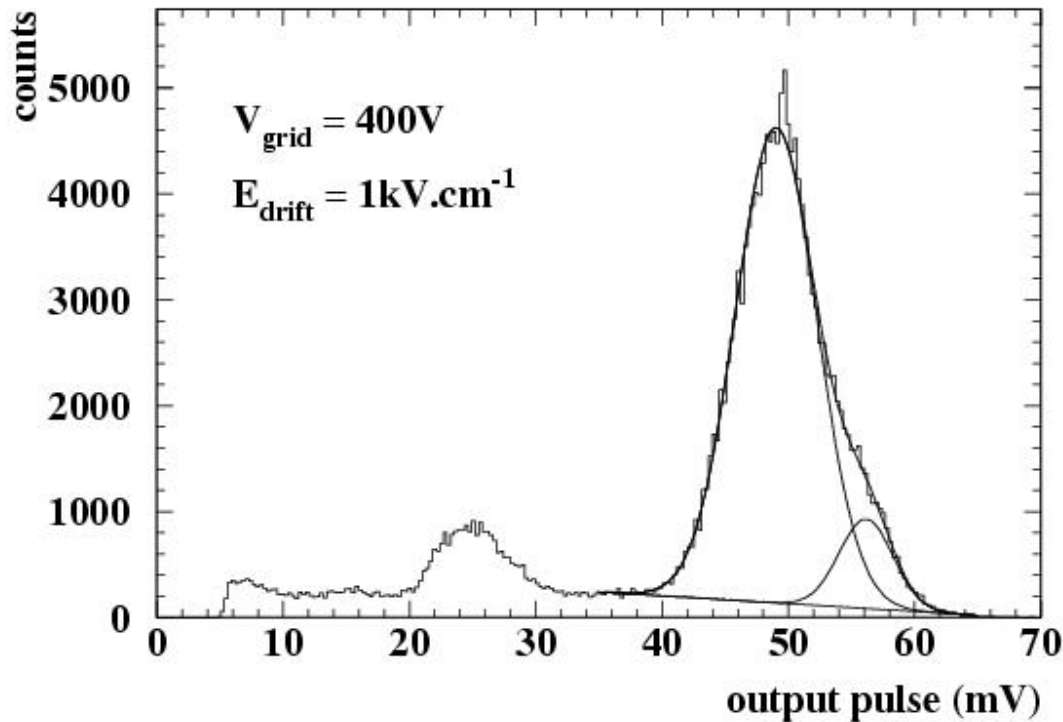
Pulseheight and gain: He + 20% iC₄H₁₀



• Gas gains $10^3 - 6 \cdot 10^4$

Energy resolution in Argon IsoC₄H₁₀ 80/20

⁵⁵Fe spectrum in Argon + 20% iC₄H₁₀



- Observation of two lines:

K_{α} at 5.9 keV

K_{β} at 6.4 keV

- Resolution $\sigma_E/E = 6.5\%$

(FWHM = 15.3%)

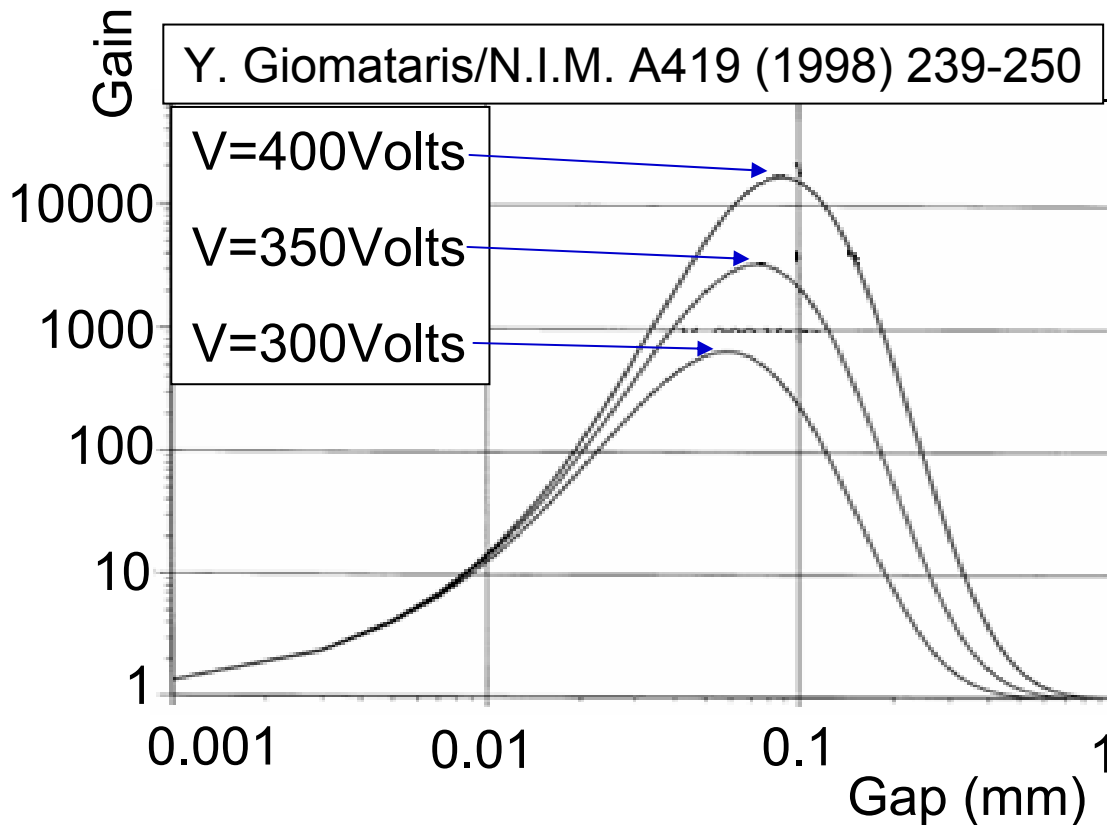
- Gain variations $< \pm 5\%$

- Photo peak asymmetry seen

- Very good energy resolution

Gain for different gap sizes

Maximum predicted in gain vs gap curve



$$M = e^{\alpha d}$$

d gap thickness

$$\alpha = pAe^{-Bp/E}$$

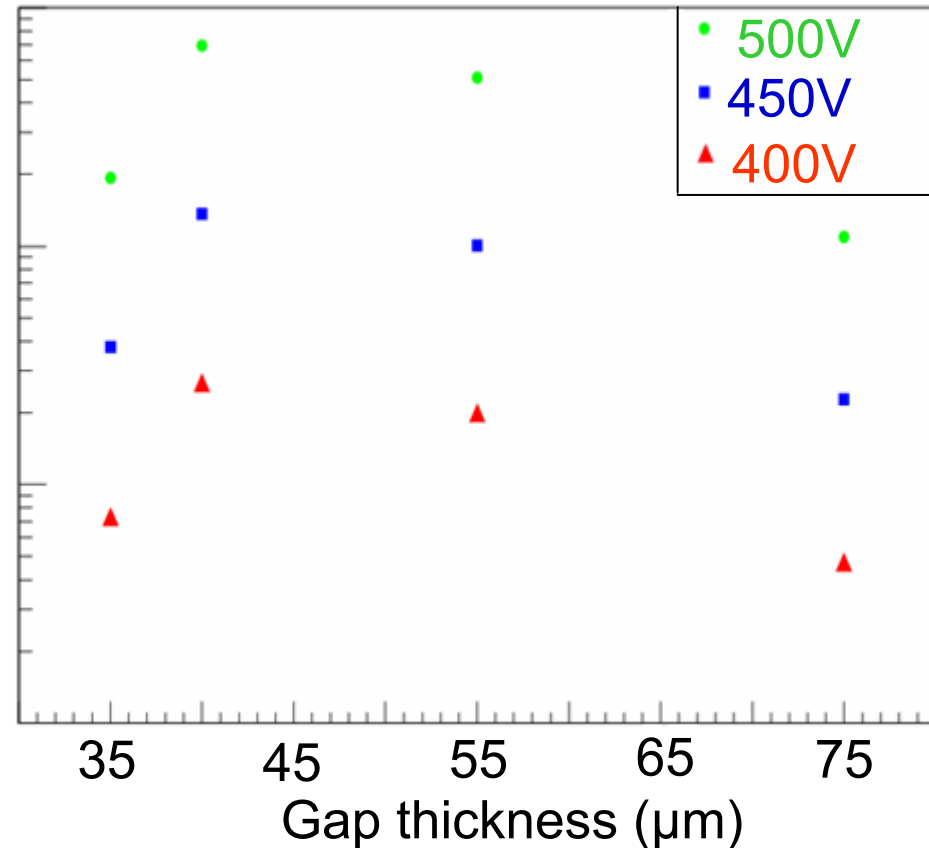
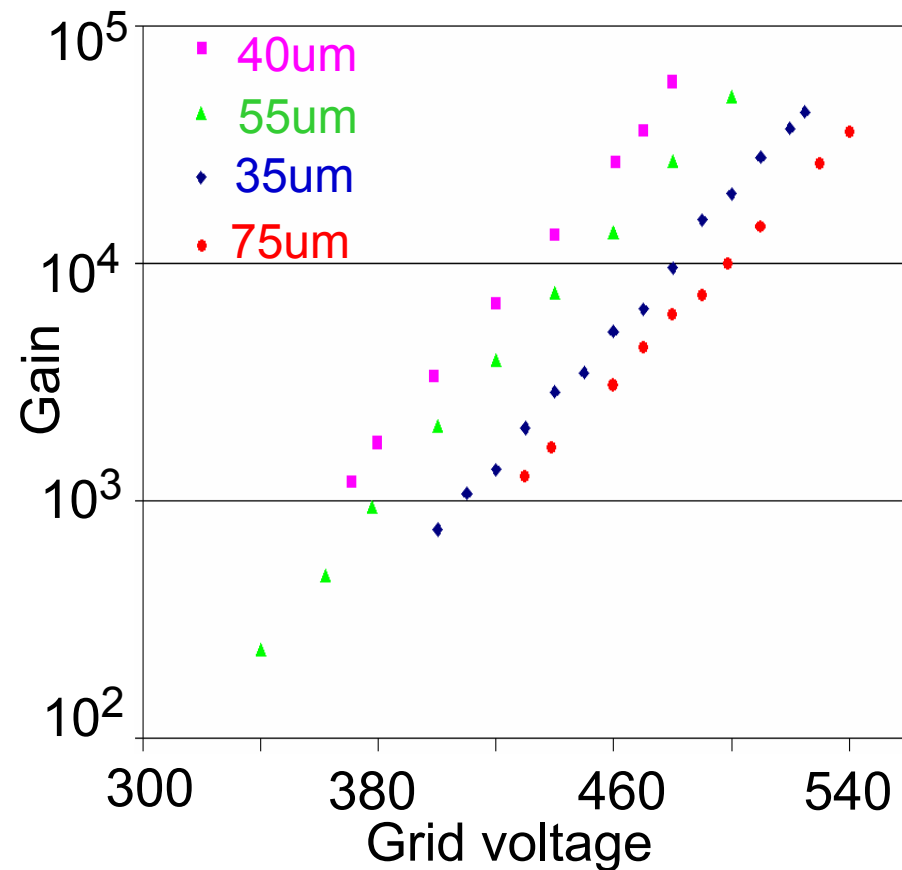
Rose & Korff

p pressure

A, B depend on gasmixture

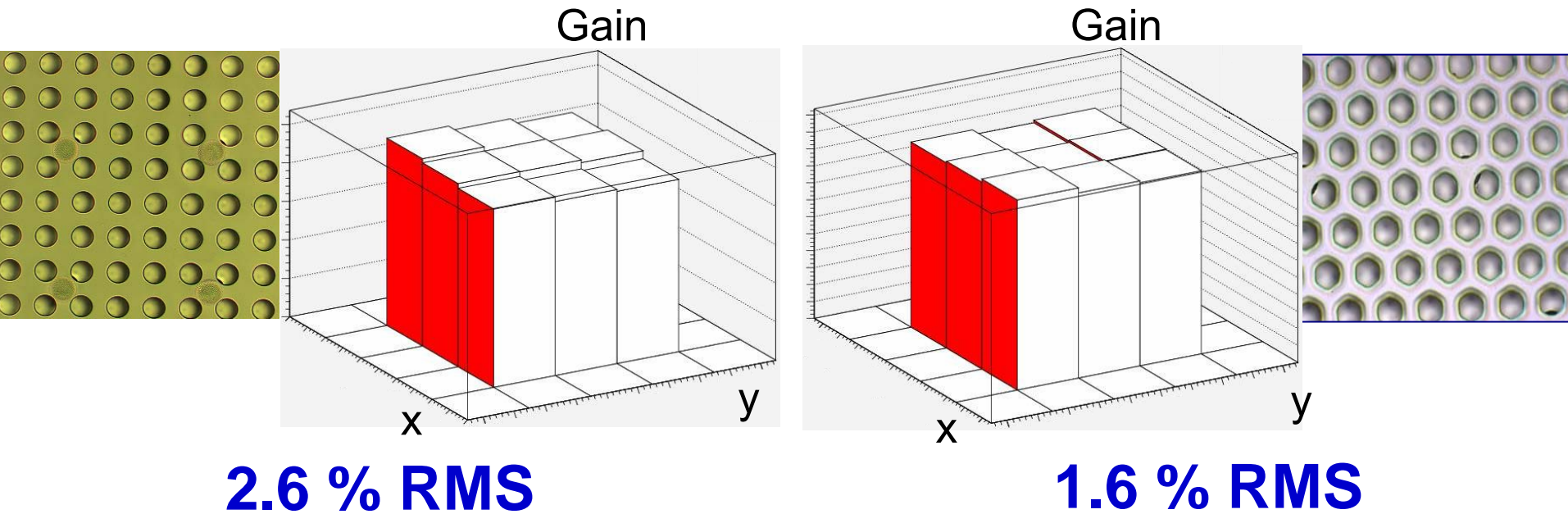
Gain for different gap sizes

- But now we can make measurements



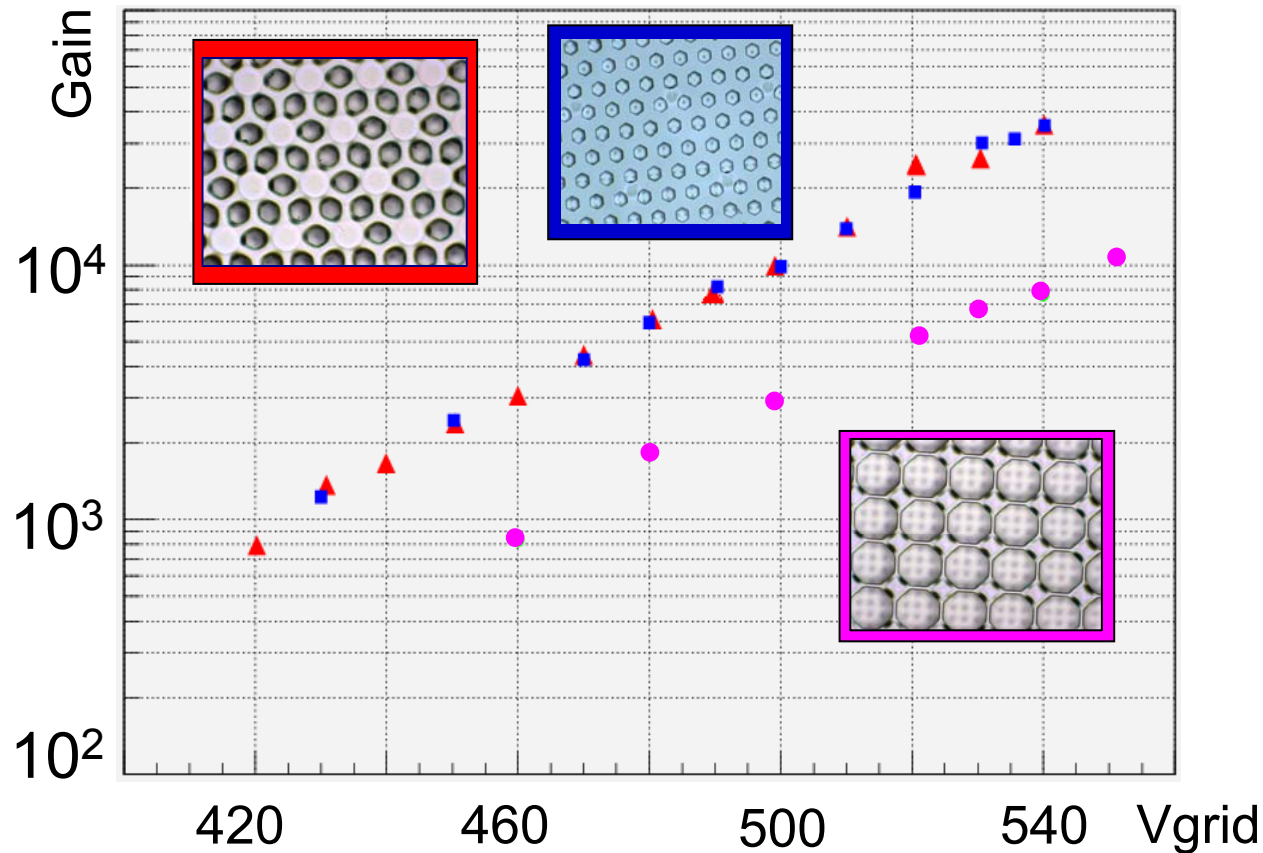
Homogeneity

- Gain measurements scanning the surface of the detector
- Homogeneity given by grid quality



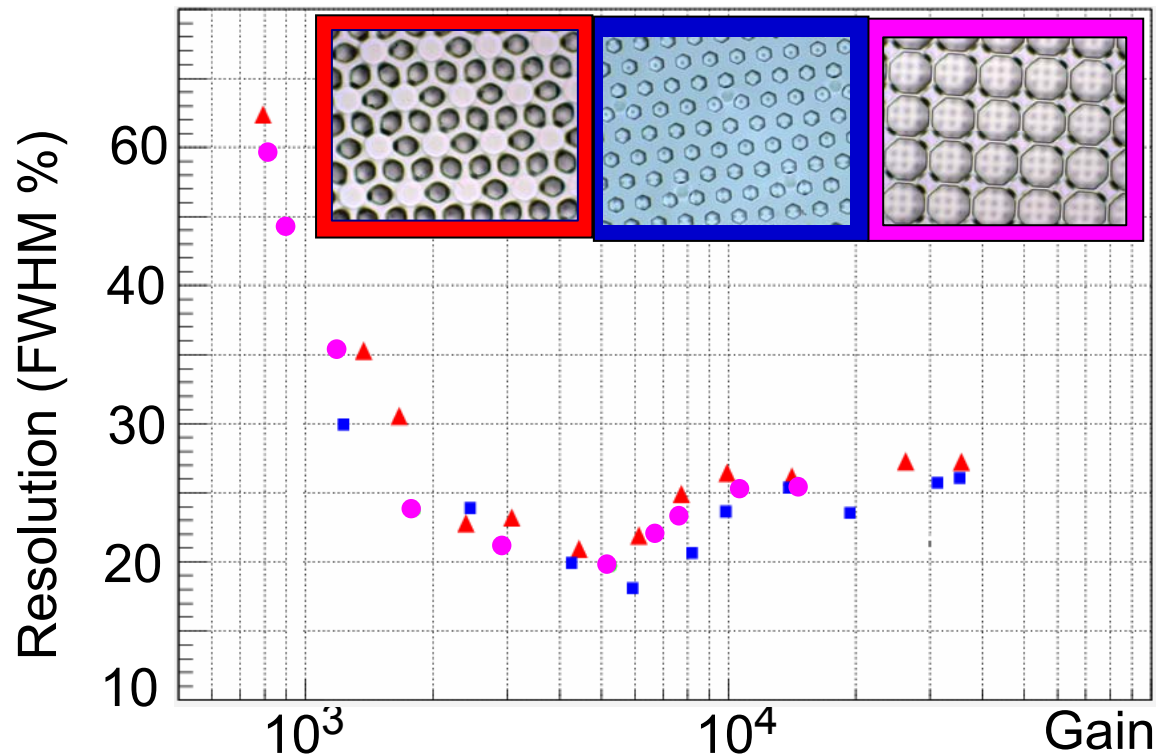
Measured gain for different hole size

And measurements confirm simulations



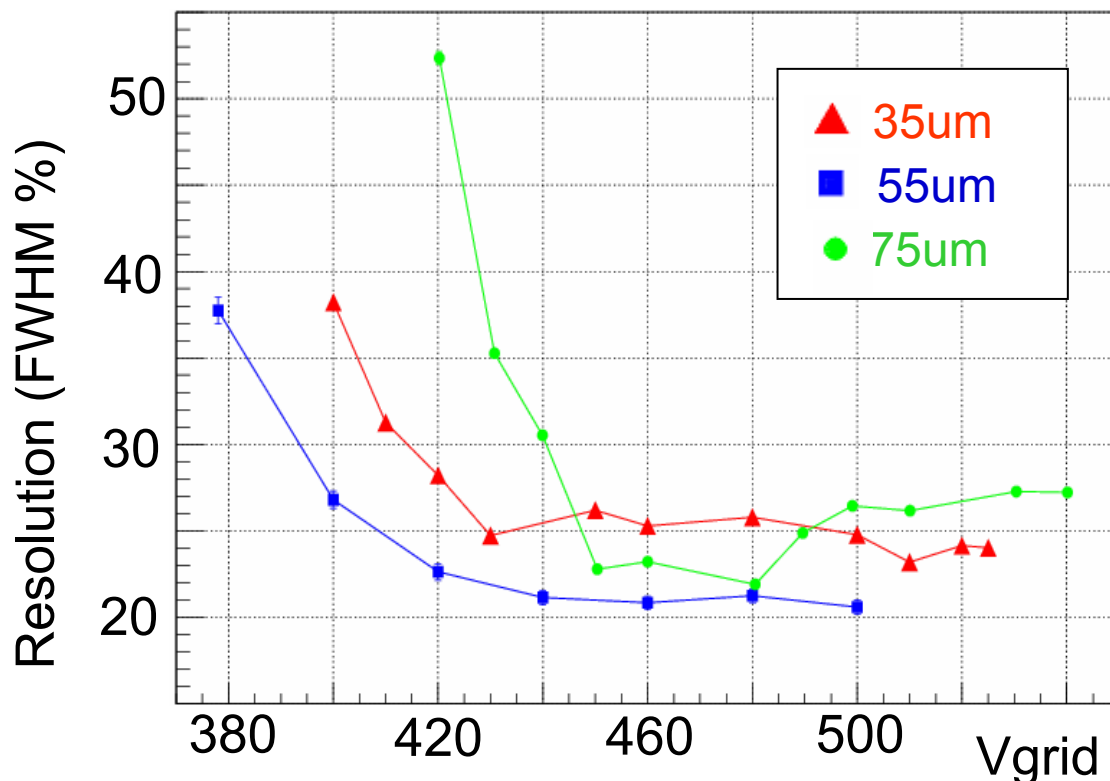
Energy resolution

- Resolution depends on
 - Primary, attachment, T,P
 - Collection efficiency (field ratio)
 - Gain homogeneity & transverse diffusion

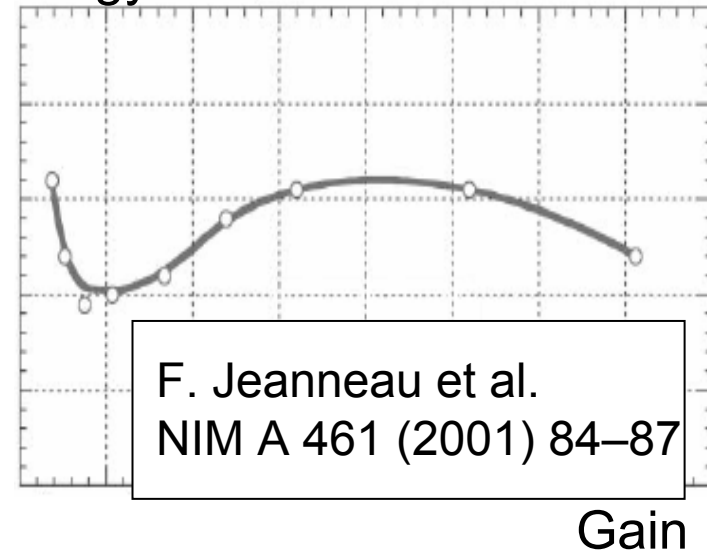


Resolution as function of gap

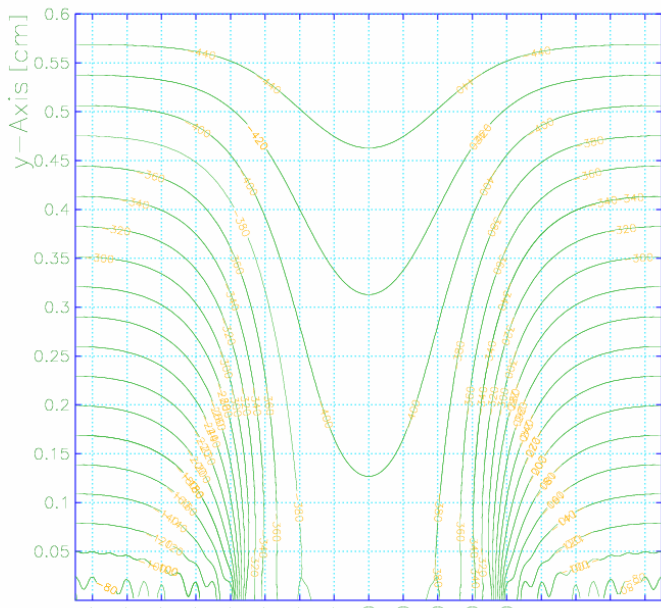
- Why a parabolic behavior ?



Energy resolution



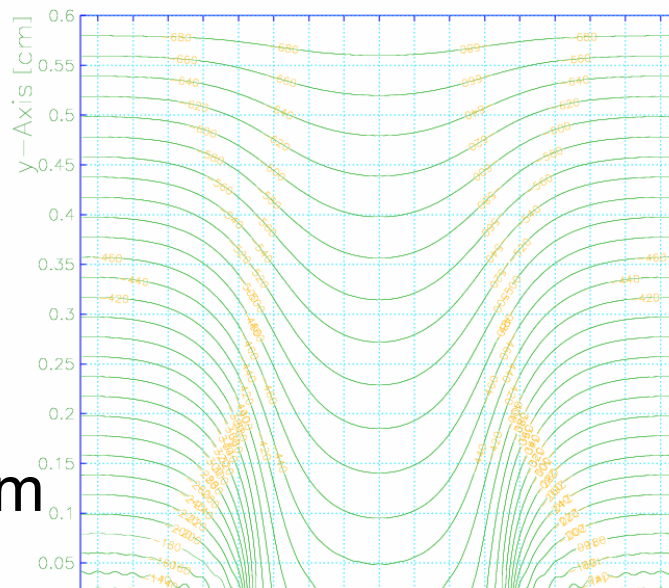
Contours of V



Plotted at 16:12:25 on 21/12/06 with Gortfield version 7.13.

100 V/cm

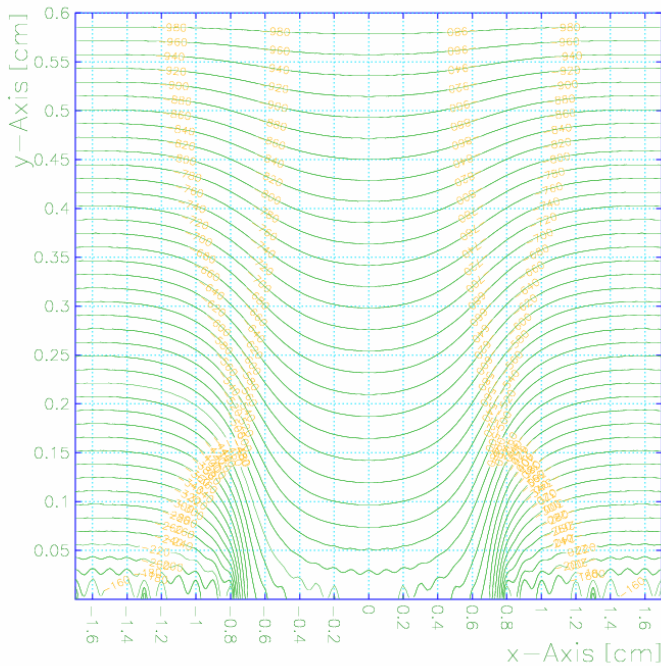
Contours of V



Plotted at 16:12:44 on 21/12/06 with Gortfield version 7.13.

500 V/cm

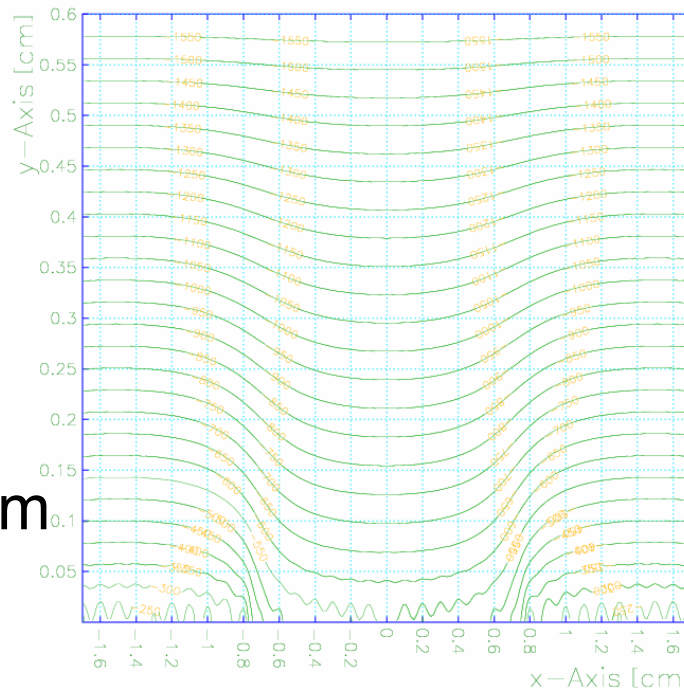
Contours of V



Plotted at 16:12:30 on 21/12/06 with Gortfield version 7.13.

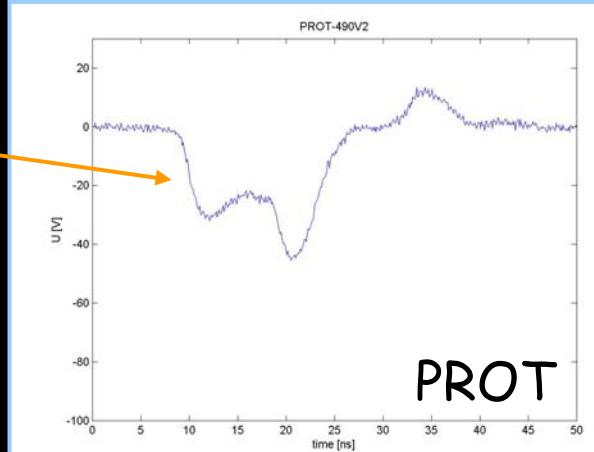
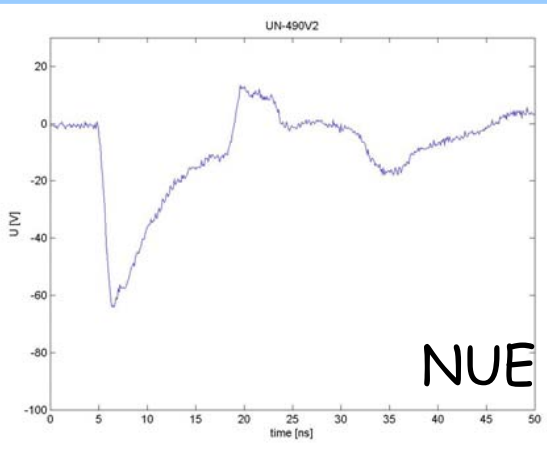
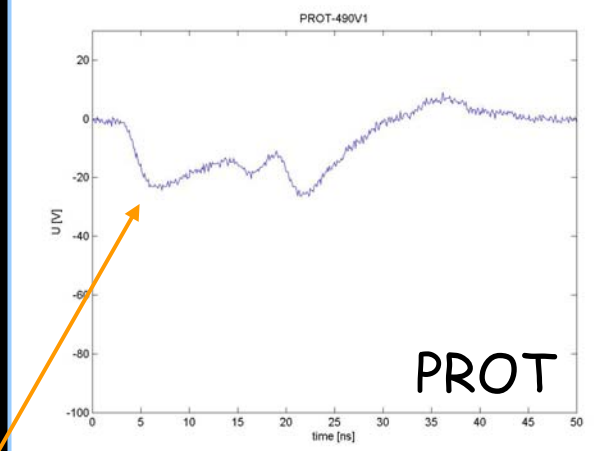
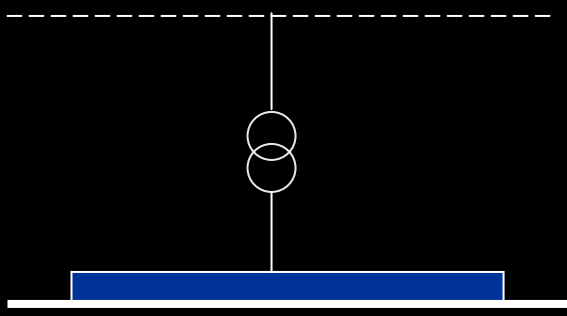
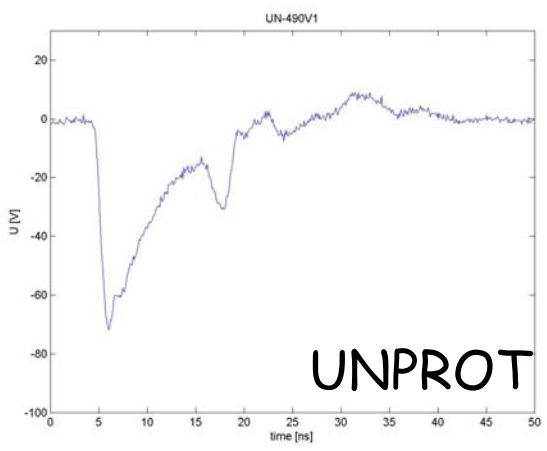
1 kV/cm

Contours of V

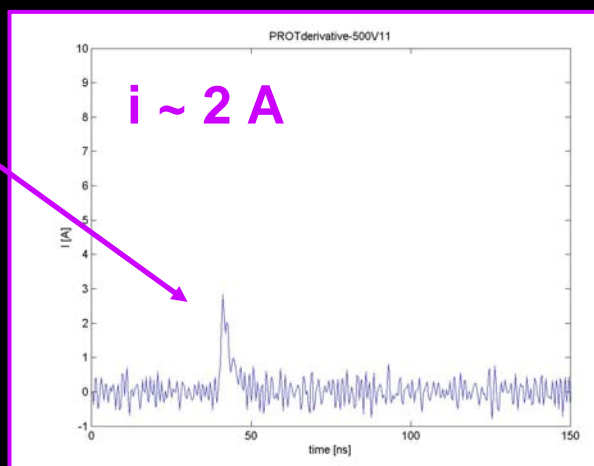
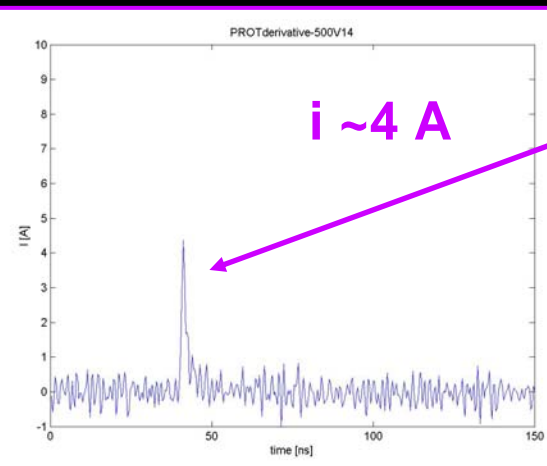


Plotted at 16:11:42 on 21/12/06 with Gortfield version 7.13.

2 kV/cm



Slope less steep for protected anode



Current reduced

Enough to protect the chip?

Tracking Review Beijing

TripleGrid

